

# ESD5V0SxUS

# Multi-Channel TVS Diode Array

- ESD / transient protection of data and power lines in 3.3 V / 5 V application according to: IEC61000-4-2 (ESD): ± 30 KV (contact) IEC61000-4-4 (EFT): 80 A (5/50 ns) IEC61000-4-5 (Surge): 10 A (8/20 μs)
- Working voltage: 5 V (5.3 V max.)
- Low clamping voltage
- Low reverse current < 5  $\mu$ A
- Pb-free (RoHS compliant) package

## Applications

- Uni or bi-directional operation possible (see application example page 5)
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and desktop computers, peripherals



### ESD5V0S4US

М

### ESD5V0S5US

5

# ESD5V0S5US E6727

180° rotated in reel

3	2	L
Γ <del> </del> <del> </del>	¥	¥
¥		¥
4	g	9

Туре	Package	Configuration	Marking
ESD5V0S4US	SOT363	4 lines, uni-directional	E4s
ESD5V0S5US	SOT363	5 lines, uni-directional	E5s
ESD5V3S5US E6727*	SOT363	5 lines, uni-directional	on request

\* Preliminary data



### **Maximum Ratings** at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit			
ESD contact discharge per diode <sup>1)</sup>	V <sub>ESD</sub>	30	kV			
Peak pulse current ( $t_p = 8 / 20 \ \mu s$ ) per diode <sup>2</sup> )	I <sub>pp</sub>	10	А			
Peak pulse power ( $t_p = 8 / 20 \ \mu s$ ) per diode	P <sub>pk</sub>	130	W			
Operating temperature range	T <sub>op</sub>	-55125	°C			
Storage temperature	T <sub>stq</sub>	-65150				

## **Electrical Characteristics** at $T_A = 25^{\circ}$ C, unless otherwise specified

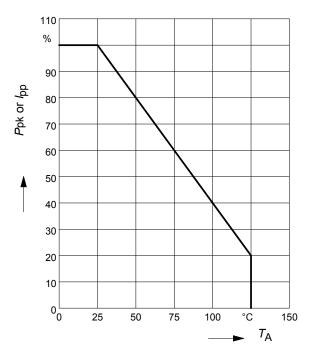
Parameter	Symbol	Values			Unit
		min.	typ.	max.	]
Characteristics -					
Reverse working voltage	V <sub>RWM</sub>	-	5	5.3	V
Breakdown voltage	V <sub>(BR)</sub>	5.7	6.7	7.7	
<i>l</i> <sub>(BR)</sub> = 1 mA					
Reverse current	I <sub>R</sub>				μA
V <sub>R</sub> = 3.3 V		-	-	1	
$V_{R}$ = 5 V		-	-	5	
Clamping voltage (positive transients)	V <sub>CL</sub>				V
$I_{\rm PP}$ = 1 A, $t_{\rm p}$ = 8/20 µs <sup>2</sup> )		-	7	9	
$I_{\rm PP} = 10 \text{ A}, t_{\rm p} = 8/20 \ \mu \text{s}^{2}$		-	10.5	13	
Forward clamping voltage (negative transients)	V <sub>FC</sub>				
$I_{\rm PP}$ = 1 A, $t_{\rm p}$ = 8/20 µs <sup>2</sup> )		-	1	3	
$I_{\rm PP} = 10 \text{ A}, t_{\rm p} = 8/20 \ \mu \text{s}^{2}$		-	3.5	6	
Diode capacitance	CT				pF
$V_{\rm R}$ = 0 V, <i>f</i> = 1 MHz		-	70	90	
$V_{\rm R}$ = 5 V, <i>f</i> = 1 MHz		-	35	55	

 $^{1}V_{\text{ESD}}$  according to IEC61000-4-2

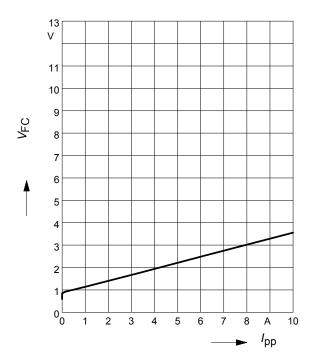
 $^2\textit{I}_{pp}$  according to IEC61000-4-5



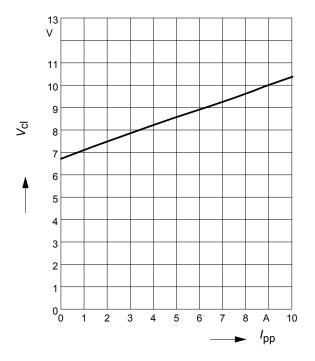
Power derating curve  $P_{pk} = f(T_A)$ 



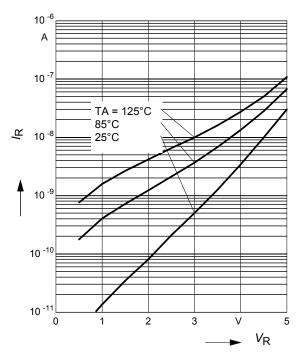
Forward clamping voltage  $V_{FC} = f (I_{pp})$  $t_p = 8 / 20 \ \mu s$  (negative transients)



**Clamping voltage**,  $V_{cl} = f(I_{pp})$  $t_p = 8 / 20 \ \mu s$  (positive transients)



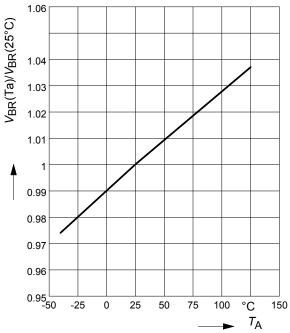
**Reverse current**  $I_{R} = f(V_{R})$  $T_{A}$  = Parameter





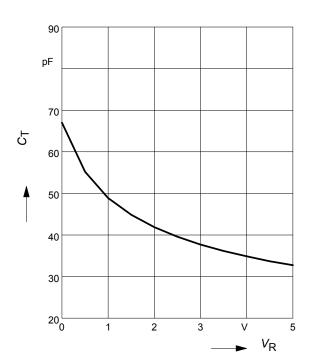
# Normalized reverse voltage

 $V_{BR}(T_A)/V_{BR}(25^{\circ}C)=f(T_A)$  $I_R = 1 \text{ mA}$ 



**Diode capacitance**  $C_{T} = f(V_{R})$ 

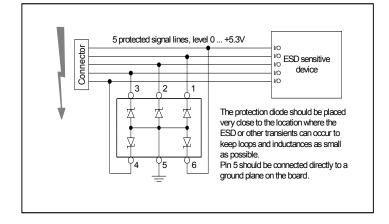
f = 1 MHz





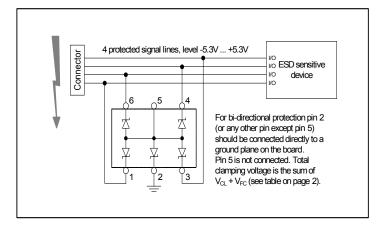
### Application example ESD5V0S5US

5 channels, uni-directional



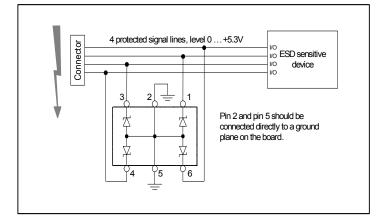
### Application example ESD5V0S5US

4 channels, bi-directional

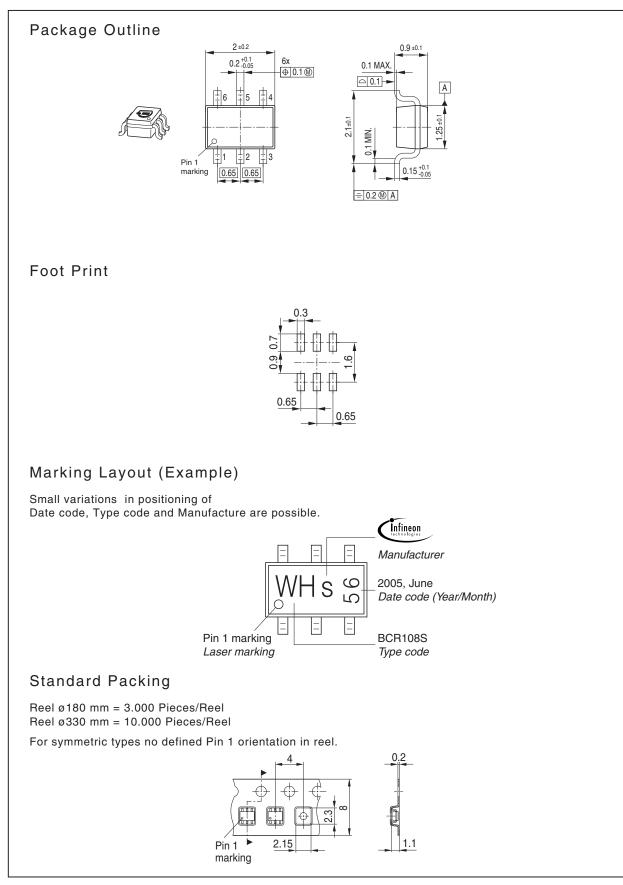


### Application example ESD5V0S4US

4 channels, uni-directional









Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

### Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

#### Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<<u>www.infineon.com</u>>).

#### Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.